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Cmel. group III element in the periodic table, is used for the thin-film layer of the structure shown in Fig. 1.

Page 9, lines 11-18, delete current paragraph and insert therefor:

03 In this example, calcium fluoride was used by deposition as the thin-film layer; however, lithium fluoride may also be used. In addition, a fluoride or an oxide of an alkali metal, such as lithium, sodium, or potassium; a fluoride or an oxide of an alkaline earth metal, such as beryllium, magnesium, calcium, or scandium; and a fluoride or an oxide of a group III element in the periodic table, such as boron, aluminum, or gallium, may also be used. In addition, a material that has adequate electrical insulating properties, easy film formability, and suppression of unnecessary current which does not contribute to light emission, may also be used.

IN THE CLAIMS:

Please cancel claims 39, 41 and 42 without prejudice or disclaimer.

15. (Amended) An electroluminescent device, comprising:  
a light-emitting layer including at least an organic polymer and disposed between an anode and a cathode; and  
means for suppressing current flowing through the light-emitting layer and not contributing to light emission disposed at at least one of a position between the light-emitting layer and the anode, and a position between the light-emitting layer and the cathode.

16. (Amended) The electroluminescent device according to claim 15, the means for suppressing current flowing through the light-emitting layer and not contributing to light emission being disposed only between the cathode and the light-emitting layer.

17. (Amended) The electroluminescent device according to claim 15, the means for suppressing current flowing through the light-emitting layer and not contributing to light emission including at least one material selected from the group consisting of a fluoride or an

oxide of an alkali metal, a fluoride or an oxide of an alkaline earth metal, and a fluoride or an oxide of a group III element in the periodic table.

18. (Amended) The electroluminescent device according to claim 16, the means for suppressing current flowing through the light-emitting layer and not contributing to light emission including at least one material selected from the group consisting of a fluoride or an oxide of an alkali metal, a fluoride or an oxide of an alkaline earth metal, and a fluoride or an oxide of a group III element in the periodic table.

19. (Amended) The electroluminescent device according to claim 15, the means for suppressing current flowing through the light-emitting layer and not contributing to light emission being disposed only between the anode and the light-emitting layer.

28. (Amended) An electroluminescent device, comprising:

a light-emitting layer including at least an organic polymer and disposed between an anode and a cathode, the light-emitting layer including the organic polymer being formed by a printing method; and

means for suppressing current flowing through the light-emitting layer and not contributing to light emission disposed at at least one of a position between the light-emitting layer and the anode, and a position between the light-emitting layer and the cathode.

29. (Amended) The electroluminescent device according to claim 28, the means for suppressing current flowing through the light-emitting layer and not contributing to light emission being disposed only between the cathode and the light-emitting layer.

30. (Amended) The electroluminescent device according to claim 28, the means for suppressing current flowing through the light-emitting layer and not contributing to light emission including at least one material selected from the group consisting of a fluoride or an oxide of an alkali metal, a fluoride or an oxide of an alkaline earth metal, and a fluoride or an oxide of a group III element in the periodic table.